March 2015



# FGH60N60SF 600 V, 60 A Field Stop IGBT

## Features

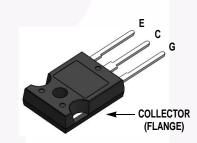
- High Current Capability
- Low Saturation Voltage: V<sub>CE(sat)</sub> = 2.3 V @ I<sub>C</sub> = 60 A
- High Input Impedance
- Fast Switching
- RoHS Compliant

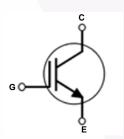
## Applications

• Solar Inverter, UPS, Welder, PFC

# **General Description**

Using novel field stop IGBT technology, Fairchild's field stop IGBTs offer the optimum performance for solar inverter, UPS, welder and PFC applications where low conduction and switching losses are essential.





## **Absolute Maximum Ratings**

Symbol	Description		Ratings	Unit
V <sub>CES</sub>	Collector to Emitter Voltage		600	V
V	Gate to Emitter Voltage		±20	V
V <sub>GES</sub>	Transient Gate-to-Emitter Voltage		±30	v
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 25°C	120	A
	Collector Current	@ T <sub>C</sub> = 100 <sup>o</sup> C	60	A
I <sub>CM (1)</sub>	Pulsed Collector Current	@ T <sub>C</sub> = 25°C	180	A
P <sub>D</sub>	Maximum Power Dissipation	wer Dissipation $@ T_C = 25^{\circ}C$		W
	Maximum Power Dissipation	@ T <sub>C</sub> = 100 <sup>o</sup> C	151	W
Т <sub>Ј</sub>	Operating Junction Temperature		-55 to +150	°C
T <sub>stg</sub>	Storage Temperature Range		-55 to +150	°C
Τ <sub>L</sub>	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	°C	

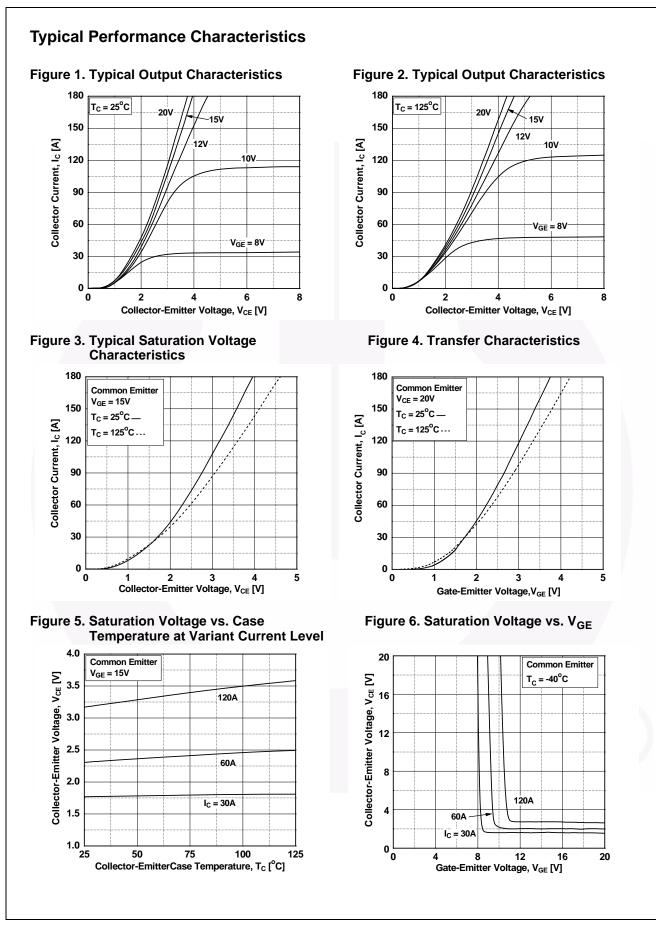
Notes:

1: Repetitive test, Pulse width limited by max. juntion temperature

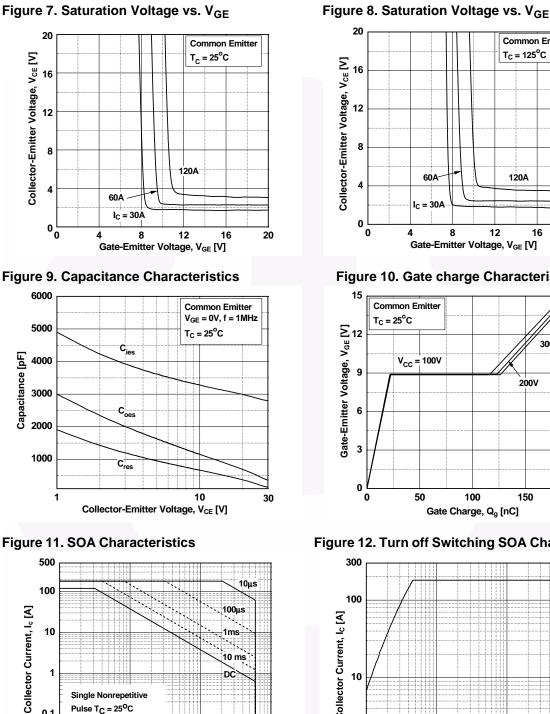
# **Thermal Characteristics**

Symbol	Parameter	Тур.	Max.	Unit	
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	-	0.33	°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	-	40	°C/W	

Part Number		Top Mark	Package	Packing Method	Reel Size	Tape Width	ı Qı	Quantity	
FGH60N60	GH60N60SFTU FGH60N60SF TO-247		Tube	N/A	N/A		30		
Electric	al Ch	aracteristic	s of the I	<b>GBT</b> $T_{C} = 25^{\circ}C$ unless othe	rwise noted				
Symbol	Parameter			Test Conditio	ns Mir	n. Тур.	Max.	Unit	
Off Charac	teristics	5						•	
BV <sub>CES</sub>	Collector to Emitter Breakdown Voltage		V <sub>GE</sub> = 0 V, I <sub>C</sub> = 250 μA	600	) -	-	V		
$\Delta BV_{CES} / \Delta T_J$	Temperature Coefficient of Breakdown Voltage		$V_{GE} = 0 \text{ V}, \text{ I}_{C} = 250 \mu\text{A}$	-	0.4	-	V/ºC		
I <sub>CES</sub>	Collect	ector Cut-Off Current		$V_{CE} = V_{CES}, V_{GE} = 0 V$	-	-	250	μA	
I <sub>GES</sub>	G-E Le	Leakage Current		$V_{GE} = V_{GES}, V_{CE} = 0 V$	-	-	±400	nA	
On Charac	1					5.0	6.5	V	
V <sub>GE(th)</sub>	G-E IN	reshold Voltage		$I_{C} = 250 \ \mu A, \ V_{CE} = V_{GE}$ $I_{C} = 60 \ A, \ V_{GE} = 15 \ V$	4.0	2.3	2.9	V	
V <sub>CE(sat)</sub> Colle	Collect	ector to Emitter Saturation Voltage		$I_{\rm C} = 60$ A, $V_{\rm GE} = 15$ V $I_{\rm C} = 60$ A, $V_{\rm GE} = 15$ V,		2.5	2.9	v	
- (,				$T_{\rm C} = 125^{\rm o}{\rm C}$	-	2.5	-	V	
					I				
Dynamic C	1				-	2820		~	
C <sub>ies</sub>	-	tt Capacitance out Capacitance erse Transfer Capacitance		V <sub>CE</sub> = 30 V <sub>,</sub> V <sub>GE</sub> = 0 V, f = 1 MHz	-	350	-	pF	
C <sub>oes</sub> C <sub>res</sub>					-	140	-	pF pF	
Ores	Revers					140		рі	
Switching	Charact	eristics							
t <sub>d(on)</sub>	Turn-O	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Turn-On Switching Loss Turn-Off Switching Loss		-	-	22	-	ns	
t <sub>r</sub>	Rise Ti				-	42	-	ns	
t <sub>d(off)</sub>	Turn-O			$V_{CC} = 400 \text{ V}, I_C = 60 \text{ A},$ $R_G = 5 \Omega, V_{GE} = 15 \text{ V},$ Inductive Load, $T_C = 25^{\circ}\text{C}$	-	134	-	ns	
t <sub>f</sub>	Fall Tin				-	31	62	ns	
Eon	Turn-O				-	1.79	-	mJ	
E <sub>off</sub>	Turn-O			H Contraction of the second	-	0.67	-	mJ	
E <sub>ts</sub>	Total S	witching Loss				2.46	-	mJ	
t <sub>d(on)</sub>	Turn-O	n Delay Time			-	22	-	ns	
t <sub>r</sub>	Rise Ti	me			-	44	- 1	ns	
t <sub>d(off)</sub>	Turn-O	ff Delay Time		$V_{\rm CC} = 400 \text{ V}, I_{\rm C} = 60 \text{ A},$	-	144	-	ns	
t <sub>f</sub>	Fall Tin	Fall Time Turn-On Switching Loss		$R_G = 5 \Omega$ , $V_{GE} = 15 V$ ,	-	43	-	ns	
E <sub>on</sub>	Turn-O			Inductive Load, $T_C = 123$	- 5°C	1.88	-	mJ	
E <sub>off</sub>	Turn-Off Switching Loss			-	1.0	-	mJ		
E <sub>ts</sub>	Total S	witching Loss			-	2.88	-	mJ	
Qg	Total G	ate Charge			-	198	-	nC	
Q <sub>ge</sub>	Gate to	Emitter Charge		$V_{CE} = 400 \text{ V}, I_{C} = 60 \text{ A},$ $V_{GE} = 15 \text{ V}$	-	22	-	nC	
Q <sub>gc</sub>	Gate to Collector Charge		GE - 10 V	-	106	-	nC		



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10 ms

1000

DC

100

Collector-Emitter Voltage, V<sub>CE</sub> [V]

# **Typical Performance Characteristics**

Common Emitter

T<sub>C</sub> = 125<sup>o</sup>C 60A-120A I<sub>C</sub> = 30A 8 12 16 20 4 Gate-Emitter Voltage, V<sub>GE</sub> [V]

Figure 10. Gate charge Characteristics

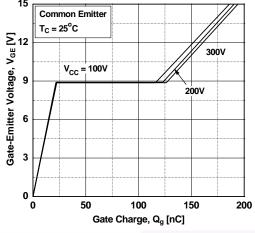
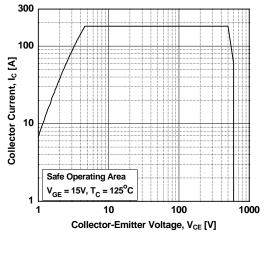


Figure 12. Turn off Switching SOA Characteristics



1

0.1

0.01

1

Single Nonrepetitive Pulse T<sub>C</sub> = 25<sup>o</sup>C

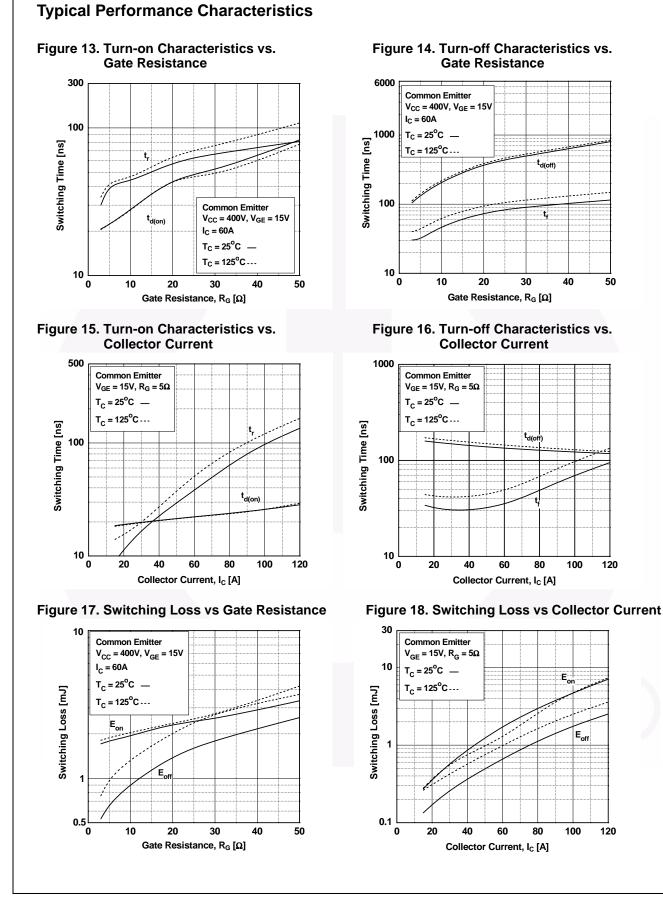
in temperature

Curves must be derated linearly with increase

10

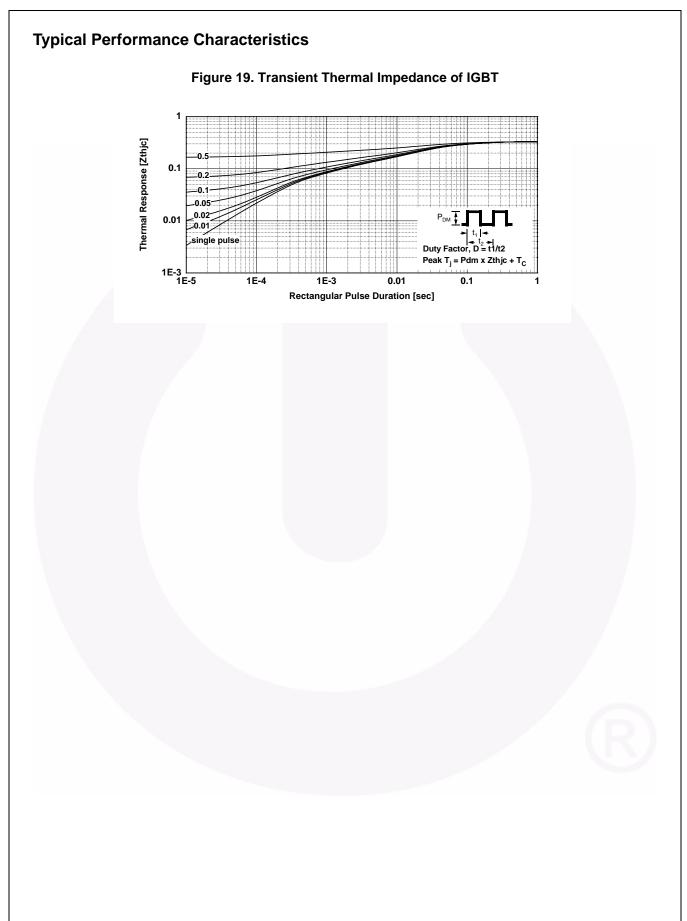
50

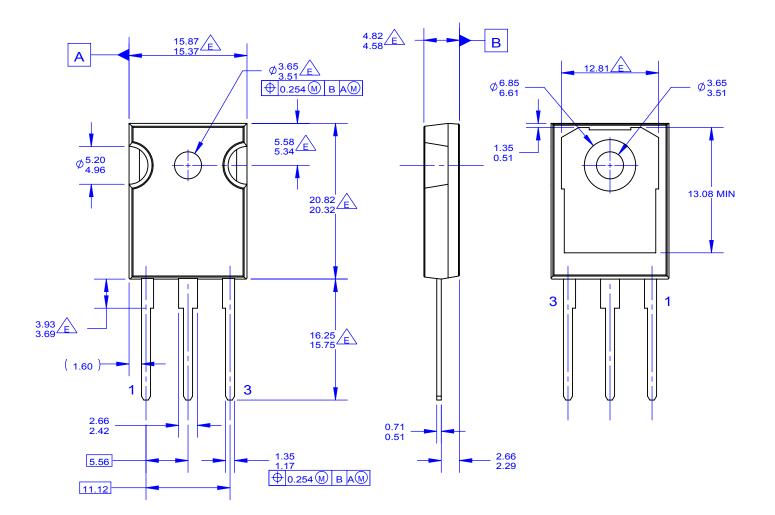
120



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120





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